



3 V SUPER MINIMOLD L-BAND SI MMIC DOWNCONVERTER

UPC2756TB

FEATURES

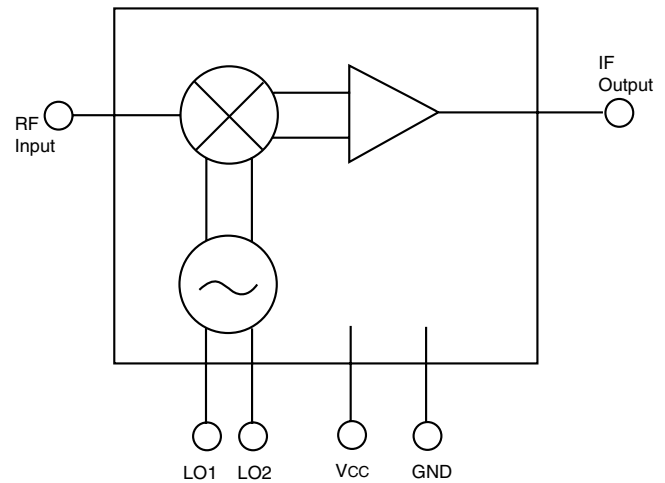
- **HIGH DENSITY SURFACE MOUNTING:**
6 Pin Super Minimold or SOT-363 package
- **WIDE BAND OPERATION:**
RF = 0.1 to 2.0 GHz
IF = 10 to 300 MHz
- **ON BOARD OSCILLATOR**
- **SUPPLY VOLTAGE:**
Vcc = 2.7 TO 3.3 V

DESCRIPTION

NEC's UPC2756TB is a silicon MMIC integrated circuit manufactured using the NESAT III process. The device consists of a double balance mixer, an IF amplifier and a built-in LO. This device is suitable as a L-BAND downconverter for the receiver stage of wireless systems. The UPC2756TB is pin compatible and has comparable performance as the larger UPC2756T, so it is suitable for use as a replacement to help reduce system size. The IC housed in a 6 pin super minimold or SOT-363 package.

NEC's stringent quality assurance and test procedures ensure the highest reliability and performance.

INTERNAL BLOCK DIAGRAM



ELECTRICAL CHARACTERISTICS (T_A = 25°C, V_{cc} = 3 V, Z_L = Z_s = 50 Ω)

PART NUMBER PACKAGE OUTLINE		UPC2756TB S06			
SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	TYP	MAX
I _{CC}	Circuit Current (no signal)	mA	3.5	6.0	8.0
f _{RF}	RF Frequency Response (3 dB down from the gain at f _{RF} = 900 MHz, f _{IF} = 150 MHz)	GHz	0.1		2.0
f _{IF}	IF Frequency Response (3 dB down from the gain at f _{RF} = 900 MHz, f _{IF} = 150 MHz)	MHz	10	300	
CG	Conversion Gain ¹ f _{RF} = 900 MHz, f _{IF} = 150 MHz f _{RF} = 1.6 GHz, f _{IF} = 20 MHz	dB dB	11 11	14 14	17 17
NF	Noise Figure f _{RF} = 900 MHz, f _{IF} = 150 MHz f _{RF} = 1.6 GHz, f _{IF} = 20 MHz	dB dB		10 13	13 16
PSAT	Saturated Output Power ² f _{RF} = 900 MHz, f _{IF} = 150 MHz f _{RF} = 1.6 GHz, f _{IF} = 20 MHz	dBm dBm	-11 -15	-8 -12	
OIP ₃	SSB Output 3rd Order Intercept Point f _{RF} = 0.8~2.0 GHz, f _{IF} = 100 MHz	dBm		+4	
ISO	LO Leakage, f _{LO} = 0.8 ~2.0 GHz at RF pin at IF pin	dBm dBm		-35 -23	
PN	Phase Noise ³ , f _{osc} = 1.9 GHz	dBc/Hz		-68	
R _{TH} (J-A)	Thermal Resistance (Junction to Ambient) Mounted on a 50 x 50 x 1.6 mm epoxy glass PWB	°C/W			325

Notes:

1. P_{RF} = -40 dBm.
2. P_{RF} = -10 dBm.
3. See Application Circuit.

ABSOLUTE MAXIMUM RATINGS¹ (T_A = 25°C)

SYMBOLS	PARAMETERS	UNITS	RATINGS
V _{CC}	Supply Voltage	V	5.5
P _T	Total Power Dissipation ²	mW	200
T _{OP}	Operating Temperature	°C	-40 to +85
T _{STG}	Storage Temperature	°C	-55 to +150

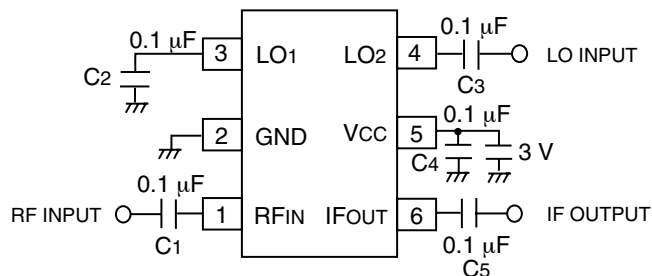
Notes:

1. Operation in excess of any one of these parameters may result in permanent damage.
2. Mounted on a 50 x 50 x 1.6 mm epoxy glass PWB (T_A = +85°C).

RECOMMENDED OPERATING CONDITIONS

SYMBOLS	PARAMETERS	UNITS	MIN	TYP	MAX
V _{CC}	Supply Voltage	V	2.7	3.0	3.3
T _{OP}	Operating Temperature	°C	-40	+25	+85

TEST CIRCUIT

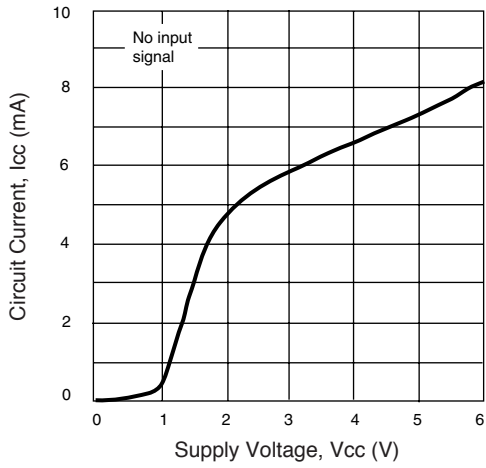


PIN FUNCTIONS

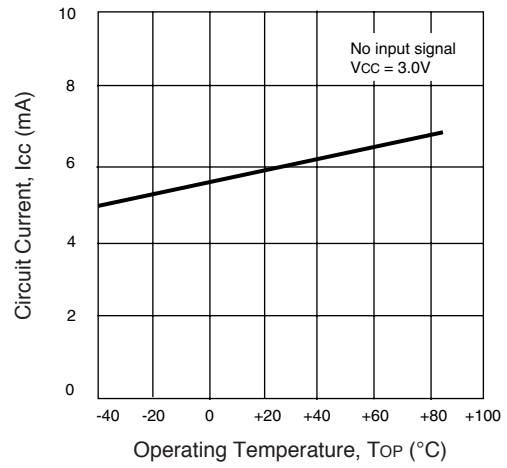
Pin No.	Symbol	Applied Voltage (V)	Pin Voltage (V)	Description	Internal Equivalent Circuit
1	RFIN	–	1.2	Signal input pin to double balanced mixer. This pin must be coupled to the signal source with a blocking capacitor.	
2	GND	0	–	Ground pin. This pin should be connected to system ground with minimum inductance. Ground pattern on the board should be formed as wide as possible.	
3	LO1	–	1.2	These pins are both the base-collectors of a differential amplifier configured to oscillate when equipped with an external tank resonator circuit. Each pin must be coupled to the tank circuit with a blocking capacitor. In the case of an external LO source, bypass the unused pin with a capacitor to ground.	
4	LO2	–	1.2		
5	VCC	2.7 to 3.3	–	Power supply pin. This pin should be externally equipped with a bypass capacitor to minimize ground impedance.	
6	IFOUT	–	1.7	Output of single-ended push-pull IF buffer amplifier. This is an emitter-follower output with low impedance. This pin must be coupled to the next stage with a blocking capacitor.	

TYPICAL PERFORMANCE CURVES (TA = 25°C)

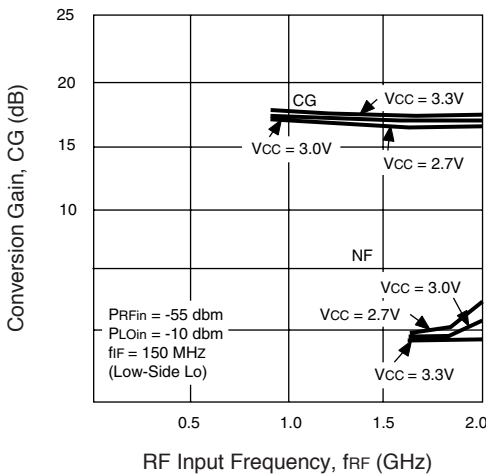
CIRCUIT CURRENT vs. VOLTAGE



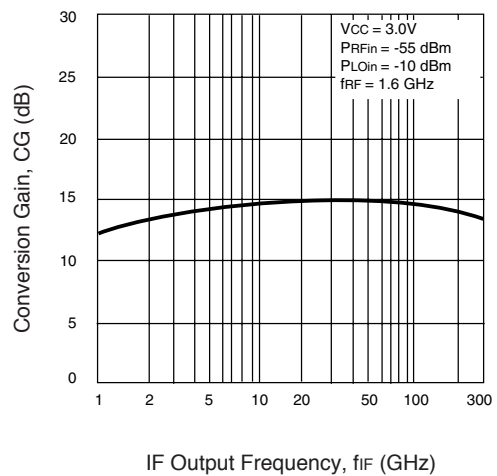
CIRCUIT CURRENT vs. TEMPERATURE



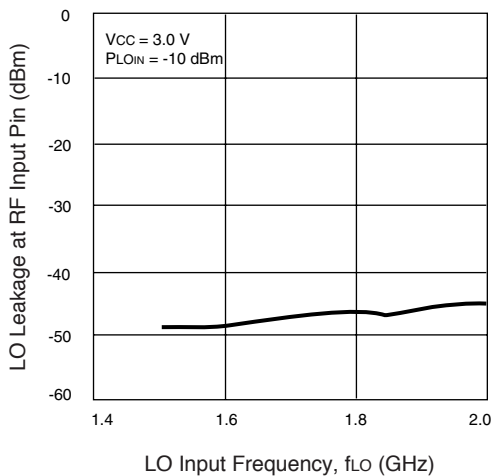
CONVERSION GAIN AND NOISE FIGURE vs. RF INPUT FREQUENCY



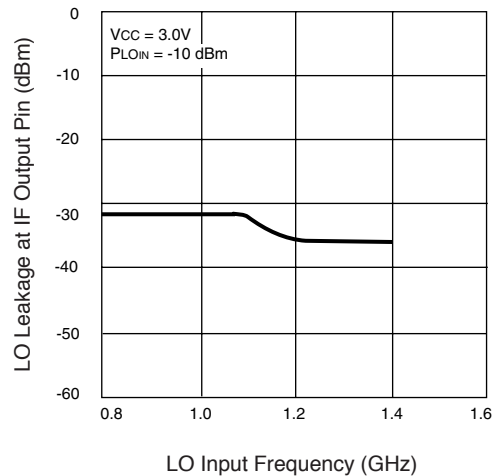
CONVERSION GAIN vs. IF OUTPUT FREQUENCY



LO LEAKAGE AT RF PIN vs. LO FREQUENCY

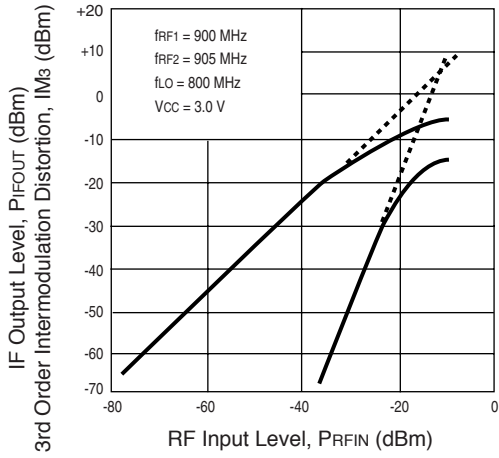


LO LEAKAGE AT IF PIN vs. LO FREQUENCY

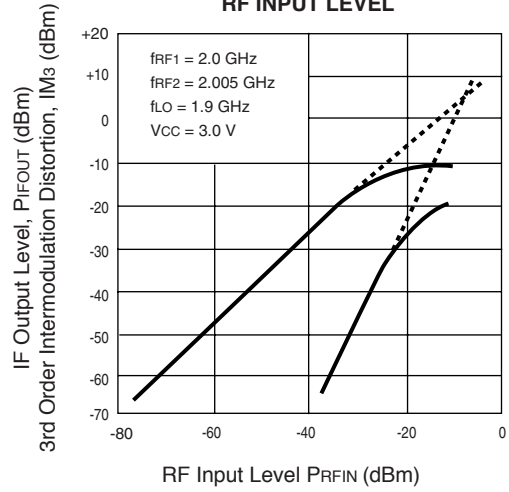


TYPICAL PERFORMANCE CURVES (TA = 25°C)

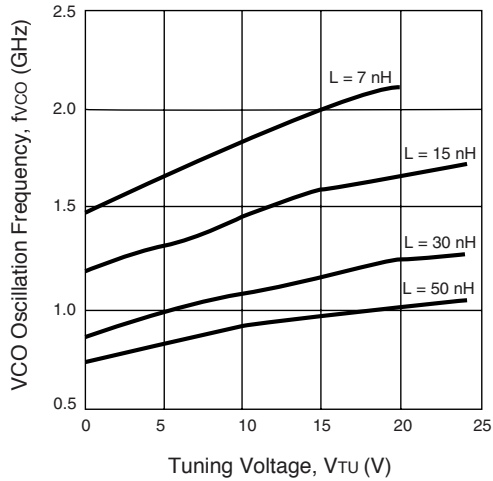
IF OUTPUT LEVEL AND IM3 vs. RF INPUT LEVEL



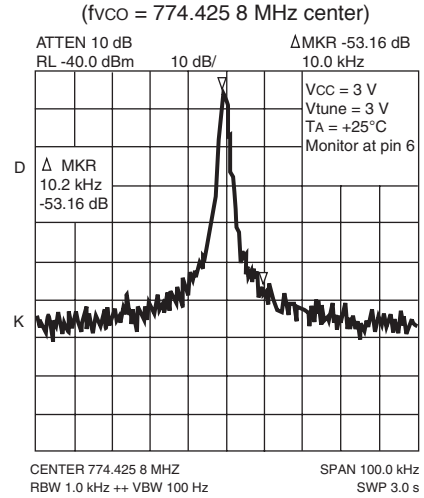
IF OUTPUT LEVEL AND IM3 vs. RF INPUT LEVEL



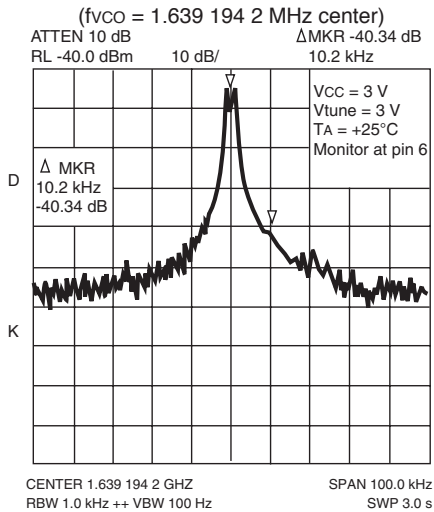
VCO OSCILLATION FREQUENCY vs. TUNING VOLTAGE



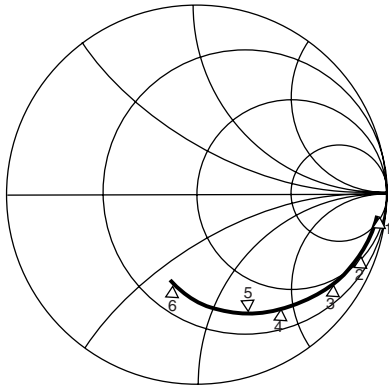
VCO PHASE NOISE



VCO PHASE NOISE

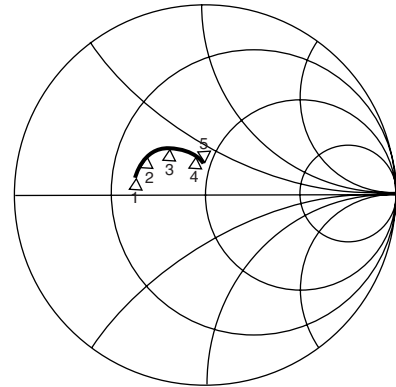


TYPICAL SCATTERING PARAMETERS



RF Port
Vcc = 3.0 V
Start 0.10 GHz
Stop 3.10 GHz

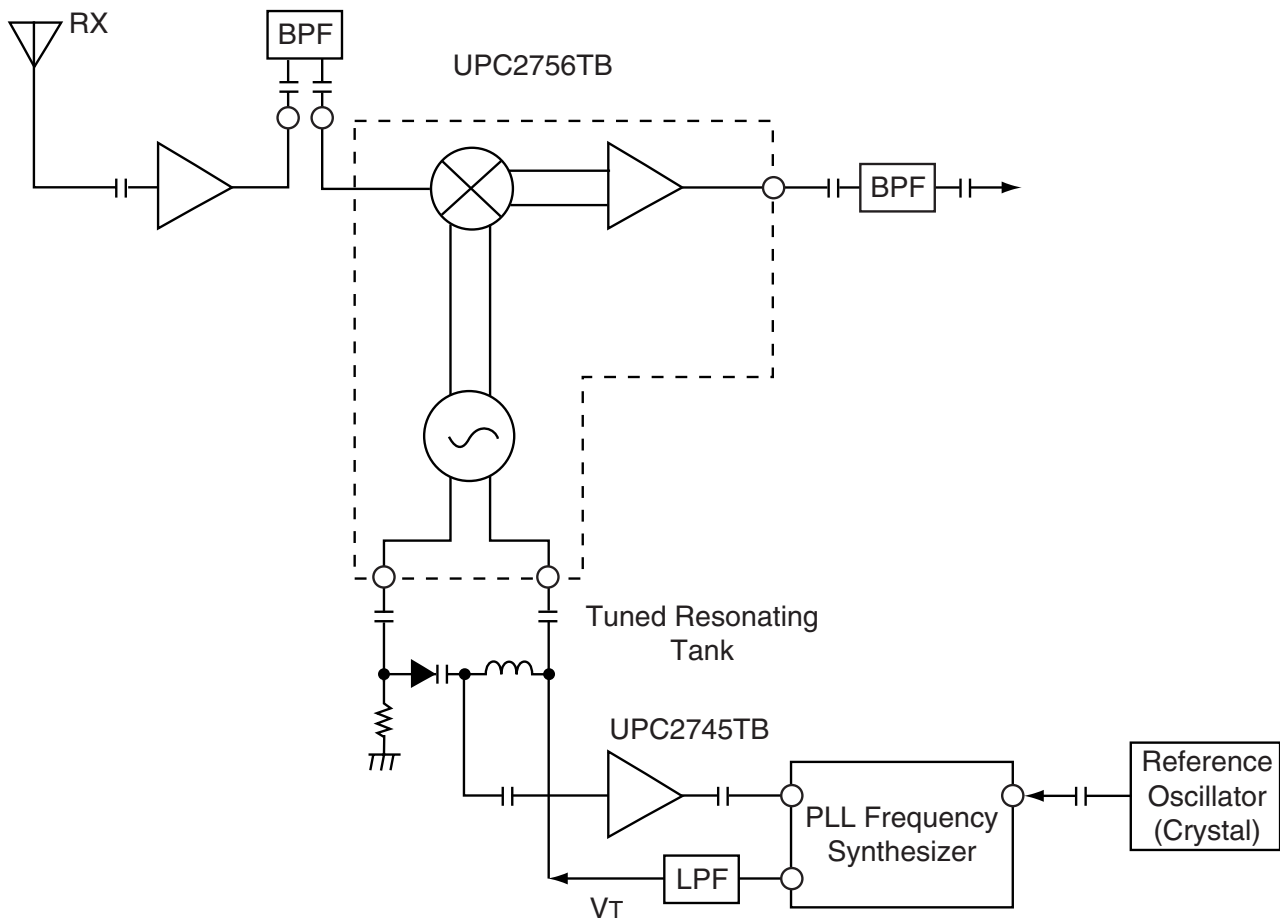
1:	100 MHz	519.8 Ω	-j 1.1 Ω
2:	500 MHz	59.3 Ω	-j 281.0 Ω
3:	900 MHz	38.3 Ω	-j 157.0 Ω
4:	1500 MHz	31.5 Ω	-j 90.1 Ω
5:	1900 MHz	28.5 Ω	-j 67.9 Ω
6:	3000 MHz	25.7 Ω	-j 31.7 Ω



RF Port
Vcc = 3.0 V
Start 0.05 GHz
Stop 3.00 GHz

1:	50 MHz	22.5 Ω	+j 6.1 Ω
2:	80 MHz	24.2 Ω	+j 11.3 Ω
3:	130 MHz	30.2 Ω	+j 16.6 Ω
4:	240 MHz	42.6 Ω	+j 17.5 Ω
5:	300 MHz	46.6 Ω	+j 15.6 Ω

SYSTEM APPLICATION EXAMPLE



Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL’s understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration contained in CEL devices	
		-A	-AZ
Lead (Pb)	< 1000 PPM	Not Detected	(*)
Mercury	< 1000 PPM	Not Detected	
Cadmium	< 100 PPM	Not Detected	
Hexavalent Chromium	< 1000 PPM	Not Detected	
PBB	< 1000 PPM	Not Detected	
PBDE	< 1000 PPM	Not Detected	

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

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